Transistors with Built-in Resistor

DRC2523E0L

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Panasonic

Silicon NPN epitaxial planar type

For digital circuits
Complementary to DRA2523E

■ Features

- Low collector-emitter saturation voltage Vce(sat)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: T1

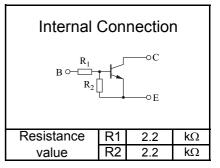
■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	VCBO	50	V
Collector-emitter voltage (Base open)	VCEO	50	V
Collector current	IC	500	mA
Total power dissipation	PT	200	mW
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

Unit: mm 2.9 0.4 0.16 (0. 95) (0. 95) 1.9 1. Base 2. Emitter 3. Collector Panasonic Mini3-G3-B JEITA SC-59A TO-236AA/SOT-23 Code



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	VCBO	IC = 10 μA, IE = 0	50			V
Collector-emitter voltage (Base open)	VCEO	IC = 2 mA, IB = 0	50			V
Collector-base cutoff current (Emitter open)	ICBO	VCB = 50 V, IE = 0			1	μΑ
Collector-emitter cutoff current (Base open)	ICEO	VCE = 50 V, IB = 0			1	μΑ
Emitter-base cutoff current (Collector open)	IEBO	VEB = 6 V, IC = 0			5	mA
Forward current transfer ratio	hFE	VCE = 10 V, IC = 100 mA	40			1
Collector-emitter saturation voltage	VCE(sat)	IC = 100 mA, IB = 5 mA			0.25	V
Input voltage	Vi(on)	VCE = 0.2 V, IC = 50 mA	2.6			V
	Vi(off)	VCE = 5 V, IC = 100 μA			0.7	V
Input resistance	R1		-30%	2.2	+30%	kΩ
Resistance ratio	R1/R2		8.0	1.0	1.2	-

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

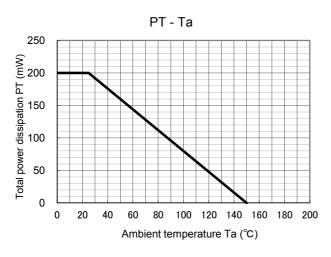
Established: 2010-02-04 Revised: 2014-03-20

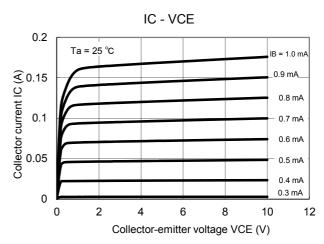
Panasonic

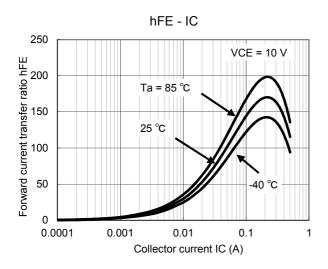
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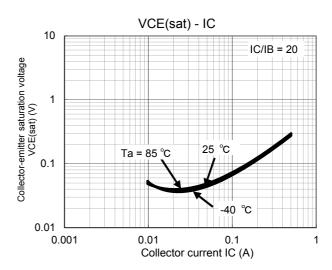
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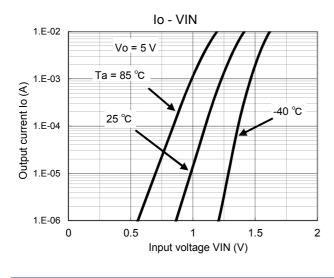
Technical Data (reference)

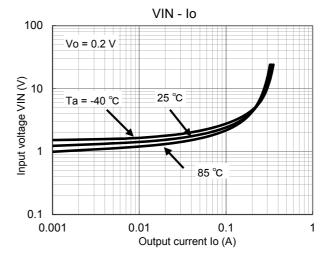












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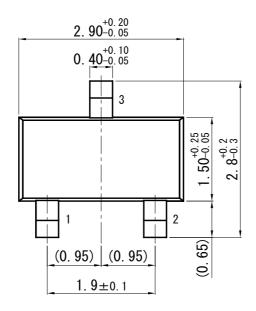
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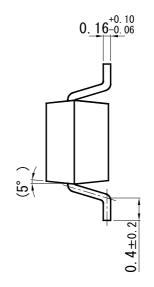
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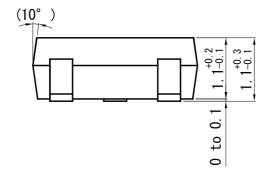
Mini3-G3-B

Panasonic

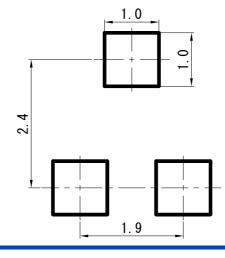
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



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